

# S-Band, GaN/SiC, 50-Ohm RF Power Transistor

2.9 - 3.4 GHz | 250 W typ | 55% Efficiency typ | 14dB Gain typ | 50 V | 150μs Pulse Length, 10% Duty Cycle

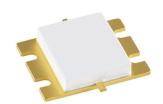
IGT2934M250 is a high power GaN-on-SiC RF power transistor that is fully matched to  $50\Omega$  at both the input and output. It supplies a minimum of 250W of peak output power, with typically >14dB of gain and 55% efficiency. It operates from a 50V supply voltage. For optimal thermal efficiency, the transistor is housed in a metal-based package with an epoxy-sealed ceramic lid.

## **FEATURES**

- GaN on SiC HEMT Technology
- Output Power 250W
- Fully matched to  $50\Omega$  at both input and output
- 100% RF Tested Under 150μs, 10% duty cycle pulse conditions
- RoHS and REACH Compliant

## **APPLICATIONS**

S-band Radar Systems



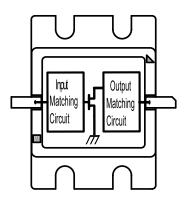


Table 1. RF Electrical Characteristics (Case temperature = 30 °C unless otherwise stated).

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Gain	G		14		dB	
Drain Efficiency	η		55		%	
Pulse Droop	D	-0.8	-0.4	+0.2	dB	P <sub>OUT</sub> = 250W f = 2.9, 3.15 3.4GHz
Input Return Loss	IRL	7	10	18	dB	150µs pulse length, 10% duty cycle
Load Mismatch Stability	VSWR-S	2:1				$V_{DS} = 50V, I_{DS} = ?$
VSWR Withstand	VSWR-LMT	3:1				
Second Harmonic			TBD		dBc	
Third Harmonic			TBD		dBc	

Note: Consult Integra Technologies Application Note 001 for information on how RF output power and pulse droop are measured.

Table 2. DC Electrical Characteristics (Case temperature = 25 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Gate Pinch-Off Voltage	V <sub>P</sub>	-4.0	-3.0	-2.5	V	$V_{DS} = 50V, I_{DS} = 2mA$
Quiescent Gate Voltage	V <sub>Q</sub>		-2.3		V	V <sub>DS</sub> = 50V, I <sub>DS</sub> = ?mA



Table 3. Absolute Maximum Ratings (Not Simultaneous). Case temperature = 25 °C unless otherwise stated.

Parameter	Symbol	Value	Units	Test Conditions
DC Drain-Source Voltage	V <sub>DS</sub>	80	V	
DC Gate-Source Voltage	V <sub>GS</sub>	-8 to +1.5	V	
DC Drain Current	I <sub>D</sub>	24	А	
DC Gate Current	I <sub>G</sub>	2.4	mA	
RF Input Power	P <sub>RE,IN</sub>	12	W	
Operating Channel Temperature	Т <sub>сн</sub>	-55 to +225	°C	
Storage Temperature	T <sub>stg</sub>	-55 to +132	°C	
Soldering Temperature	T <sub>SOLDER</sub>	260 for 10s	°C	

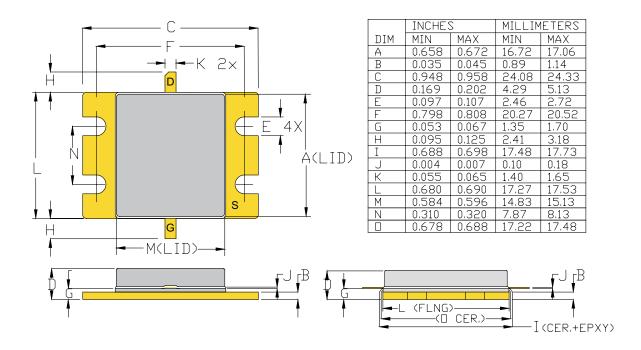
Note: Operation outside the limits given in this table may cause permanent damage to the transistor

Table 4. Thermal Resistance (Case temperature = 85 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Peak Thermal Resistance, Channel to Case	R <sub>TH</sub>		TBD		°C/W	$P_{DISS} = 205W$ 150µs pulse length, 10% duty cycle $V_{DS} = 50V$



## **PACKAGE PM67A1**





#### **ESD & MSL Rating**

Parameter	Rating	Standard		
ESD Human Body Model (HBM)	TBD	ESDA/JEDEC JS-001-2012		
ESD Charged Device Model (CDM)	TBD	JEDEC JESD22-C101F		
Moisture Sensitivty Level (MSL)	Unlimited Shelf Life	IPC/JEDEC J-STD-020		

#### **RoHS Compliance**

Integra Technologies, Inc declares that its GaN and LDMOS Transistor Products comply with EU Directive 2011/65/EU on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863/EU.

## **REACH Compliance**

Integra Technologies supports EU Regulation number 1907/2006 concerning the Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH) as these apply to Integra semiconductor products, development tools, and shipping packaging.

In support of the REACH regulation, Integra will:

- •Inform customers and recipients of Integra product if they contain any substances that are of very high concern (SVHC) per the European Chemical Agency (ECHA) website.
- •Notify ECHA if any Integra product that contains any SVHCs which exceed guidelines for REACH chemicals by weight per part number and for total content weight per year for all products produced in or imported to the European market.
- •Cease shipments of product containing REACH Annex XIV substances until authorization has been obtained.
- Cease shipment of product containing REACH Annex XVII chemicals when restrictions apply.

Integra has evaluated its materials, BOMs, and product specifications and product and has determined that this transistor conforms to all REACH and SVHC regulations and guidelines. Integra has implemented actions and control programs that will assure continued compliance.

#### Disclaimer

Integra Technologies Inc. reserves the right to make changes without further notice to any products herein. Integra Technologies Inc. makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Integra Technologies Inc. assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. Integra Technologies Inc. products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Integra Technologies Inc. customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Integra Technologies Inc. for any damages resulting from such improper use or sale.

**DEFINITIONS:** 

DATA SHEET STATUS

Advanced Specification - This data sheet contains Advanced specifications.

Preliminary Specification - This data sheet contains specifications based on preliminary measurements and data.

Final Specification - This data sheet contains final product specifications

MAXIMUM RATINGS Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.

Integra Technologies, 321 Coral Circle, El Segundo, CA 90245-4620 | Phone: 310-606-0855 | Fax: 310-606-0865